



SPH20S200

主要参数 MAIN CHARACTERISTICS

$I_{F(AV)}$	20 (2×10) A
V_{RRM}	200 V
T_j	175 °C
$V_{F(max)}$	0.8V (@ $T_j=125^{\circ}C$)

用途

- 高频开关电源
- 低压续流电路和保护电路

APPLICATIONS

- High frequency switch power supply
- Free wheeling diodes, polarity protection applications

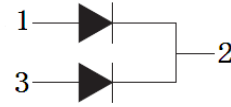
产品特性

- 共阴结构
- 低功耗，高效率
- 良好的高温特性
- 有过压保护环，高可靠性
- 环保（RoHS）产品

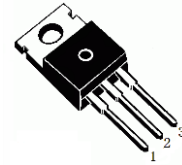
FEATURES

- Common cathode structure
- Low power loss, high efficiency
- High Operating Junction Temperature
- Guard ring for overvoltage protection, High reliability
- RoHS product

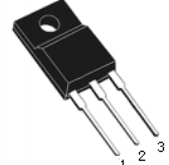
封装 Package



TO-220C



TO-220MF-K1



订货信息 ORDER MESSAGE

订 货 型 号 Order codes				印 记 Marking	封 装 Package
有卤-条管 Halogen-Tube	无卤-条管 Halogen Free-Tube	有卤-编带 Halogen-Reel	无卤-编带 Halogen Free-Reel		
SPH20S200-C-B	SPH20S200-C-BR	N/A	N/A	SPH20S200	TO-220C
SPH20S200-F1-B	SPH20S200-F1-BR	N/A	N/A	SPH20S200	TO-220MF-K1

绝对最大额定值 ABSOLUTE RATINGS ($T_c=25^{\circ}\text{C}$)

项 目 Parameter			符 号 Symbol	数 值 Value	单 位 Unit
最大反向重复峰值电压 Repetitive peak reverse voltage			V_{RRM}	200	V
最大直流阻断电压 Maximum DC blocking voltage			V_{DC}	200	V
正向平均整流电流 Average forward current	$T_C=100^{\circ}\text{C}$	整个器件 per device	$I_{F(AV)}$	20	A
		单 侧 per diode		10	
正向峰值浪涌电流 Surge non repetitive forward current (额定负载 8.3ms 半正弦波—按 JEDEC 方法) 8.3 ms single half-sine-wave (JEDEC Method)			I_{FSM}	180	A
最高结温 Maximum junction temperature			T_j	-40~+175	$^{\circ}\text{C}$
储存温度 Storage temperature range			T_{STG}	-40~+175	$^{\circ}\text{C}$

电特性 ELECTRICAL CHARACTERISTICS

项 目 Parameter	测试条件 Tests conditions		最小值 Value(min)	典型值 Value(typ)	最大值 Value(max)	单位 Unit
I_R	$T_j=25^{\circ}\text{C}$	$V_R=V_{RRM}$			10	μA
	$T_j=125^{\circ}\text{C}$				6	mA
V_F	$T_j=25^{\circ}\text{C}$	$I_F=10\text{A}$		0.85	0.94	V
	$T_j=125^{\circ}\text{C}$				0.8	V

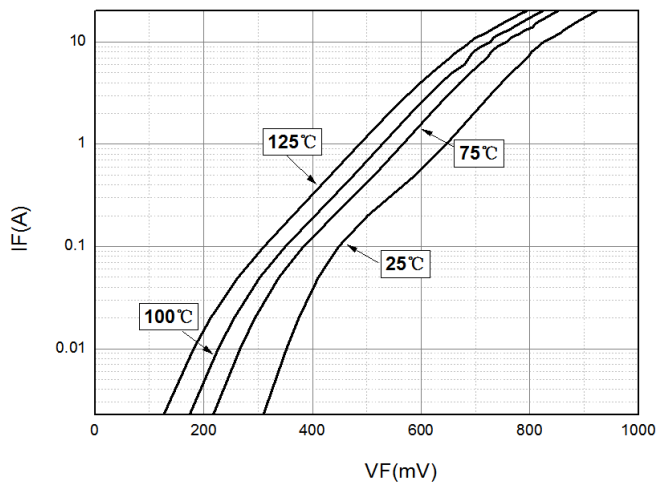
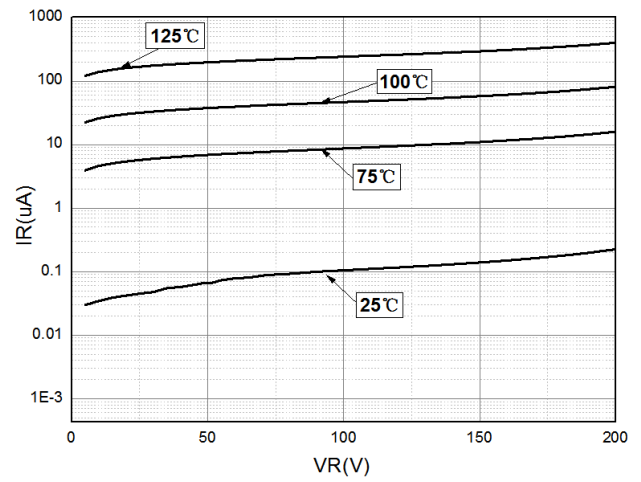
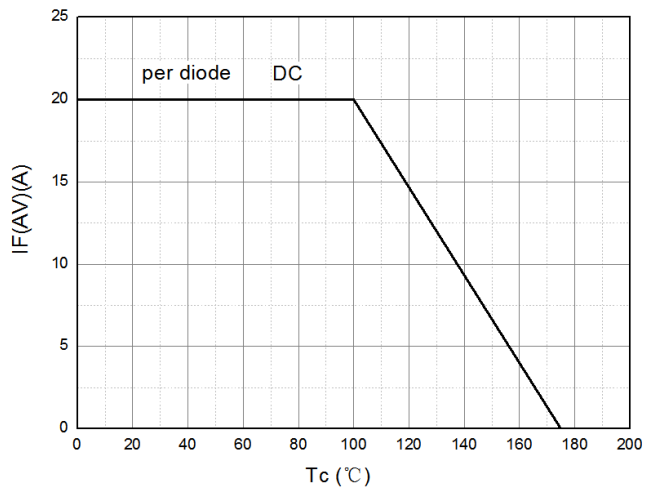
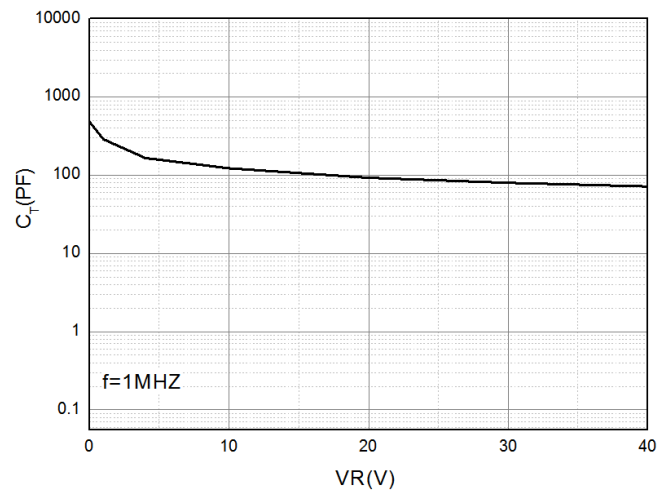
热特性 THERMAL CHARACTERISTICS

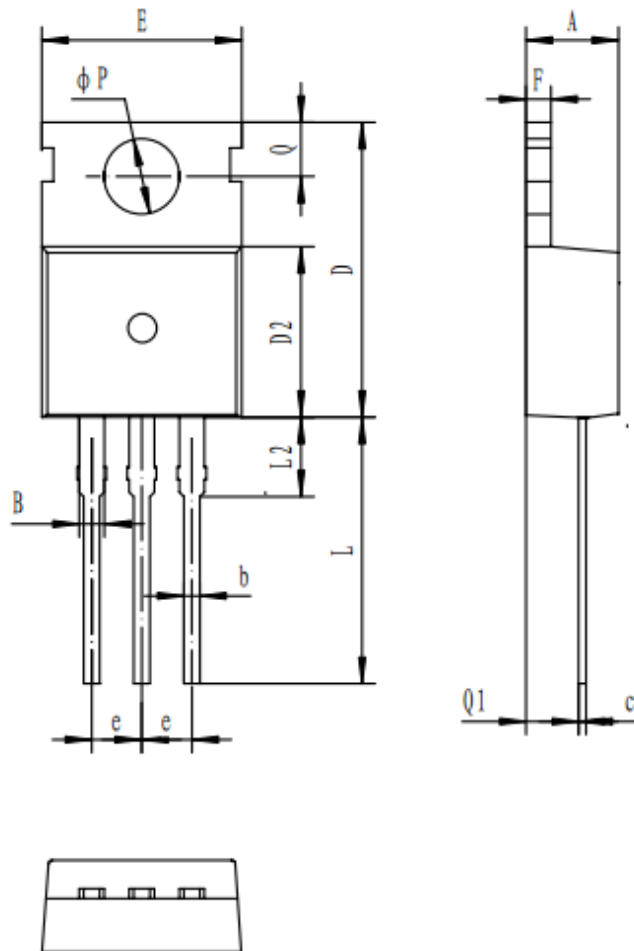
项 目 Parameter	符 号 Symbol	最小值 Value(min)	最大值 Value(max)	单 位 Unit
结到管壳的热阻 Thermal resistance from junction to case	$R_{th(j-c)}$		3.0 3.5	$^{\circ}\text{C}/\text{W}$
	TO-220C TO-220MF-K1			



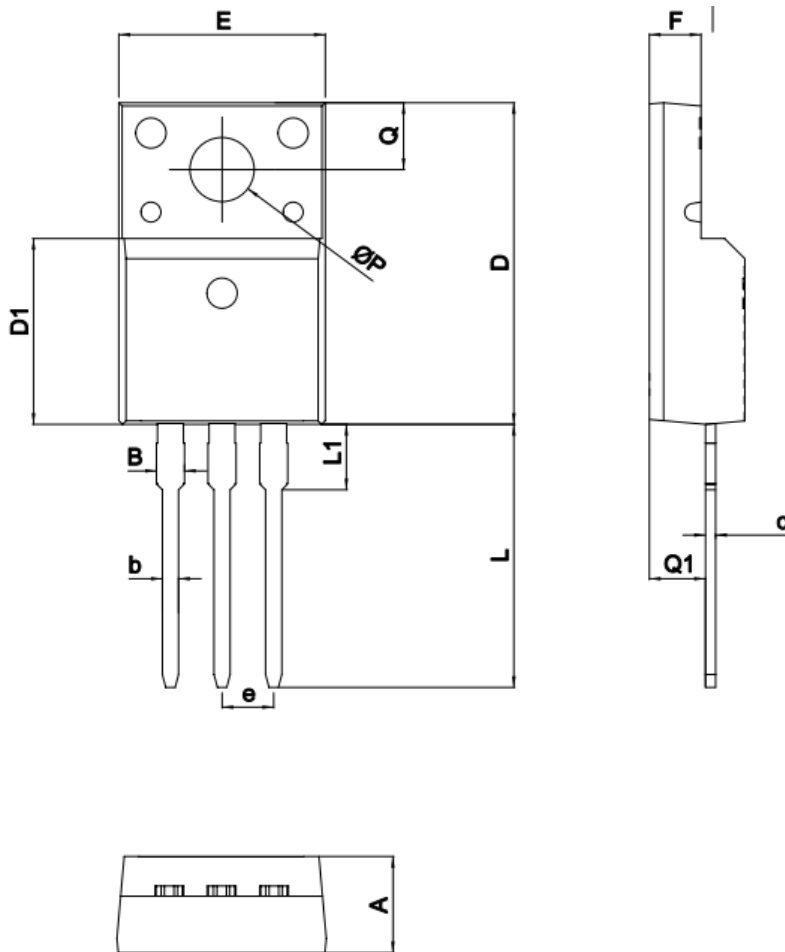


特征曲线 ELECTRICAL CHARACTERISTICS (curves)

 I_F vs V_F  I_R vs V_R  $I_F(AV)$ vs T_c  C_T vs V_R 



符号 symbol	MIN	MAX
A	4.30	4.70
B	1.10	1.40
b	0.70	0.95
c	0.40	0.65
D	15.20	16.20
D2	9.00	9.40
E	9.70	10.10
e	2.39	2.69
F	1.25	1.40
L	12.60	13.60
L2	2.80	3.20
Q	2.60	3.00
Q1	2.20	2.60
P	3.50	3.80



SYMBOL	mm	
	MIN	MAX
A	4.5	4.9
B	1.22	1.47
b	0.7	0.9
c	0.45	0.60
D	15.6	16.1
D1	9.0	9.3
e	2.54TYPE	
E	9.9	10.4
F	2.3	2.8
L	12.6	13.3
L1	3.1	3.4
Q	3.2	3.4
Q1	2.6	2.9
ΦP	3.0	3.5



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3. 在电路设计时请不要超过器件的绝对最大额定值，否则会影响整机的可靠性。
4. 本说明书如有版本变更不另外告知。

NOTE

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3. Please do not exceed the absolute maximum ratings of the device when circuit designing.
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